

MOSFET – Power, Dual N-Channel, for 1-2 Cells Lithium-ion Battery Protection

24 V, 45 mΩ, 6 A

EFC4612R-S

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1–2 cells lithium–ion battery applications.

Features

- 2.5 V Drive
- Common-Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halide Free and RoHS Compliant

Applications

• 1-2 Cells Lithium-ion Battery Charging and Discharging Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at $T_A = 25^{\circ}C$

Parameter	Symbol	Value	Unit
Source to Source Voltage	V _{SSS}	24	V
Gate to Source Voltage	V_{GSS}	±12	V
Source Current (DC)	I _S	6	Α
Source Current (Pulse) PW ≤ 10 µs, duty cycle ≤ 1%	I _{SP}	60	Α
Total Dissipation (Note 2)	P _T	1.6	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

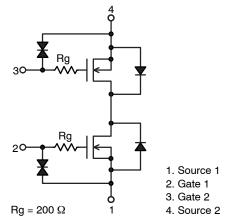
THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\theta JA}$	78.1	°C/W

^{1.} Surface mounted on ceramic substrate (5000 $\text{mm}^2\times 0.8~\text{mm}$).

V _{SSS}	R _{SS(on)} Max	I _S Max
24 V	45 mΩ @ 4.5 V	6 A
	48 mΩ @ 4.0 V	
	50 mΩ @ 3.7 V	
	57 mΩ @ 3.1 V	
	72 m Ω @ 2.5 V	

ELECTRICAL CONNECTION N-Channel





MARKING DIAGRAM

WLCSP4, 1.3 × 1.3 / EFCP1313-4CC-037 CASE 567DP



FN = Specific Device Code

Y = Year

M = Month

ZZ = Assembly Lot Number

PIN CONNECTIONS



- 1. Source 1
- 2. Gate 1
- 3. Gate 2
- 4. Source 2

ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

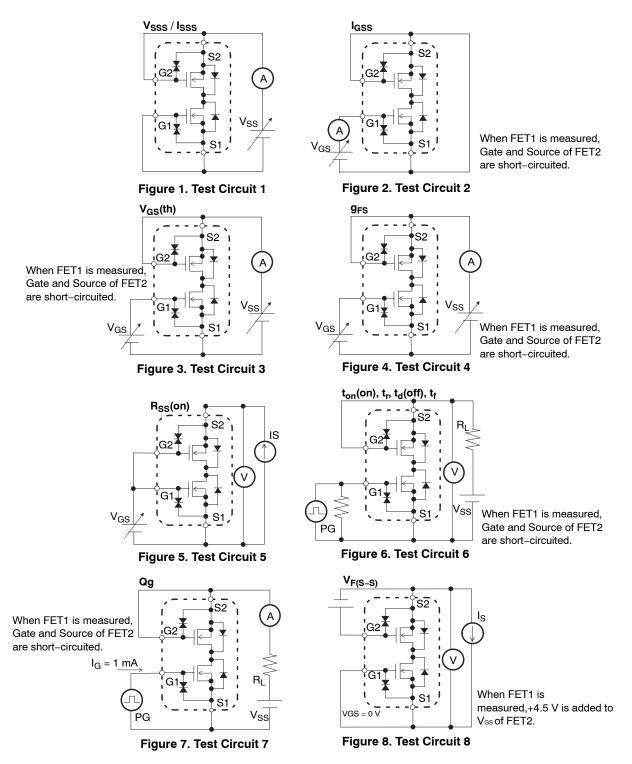
EFC4612R-S

ELECTRICAL CHARACTERISTICS at T_A = 25°C

					Value		
Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I _S = 1 mA, V _{GS} = 0 V	(Figure 1)	24	-	_	V
Zero-Gate Voltage Source Current	I _{SSS}	V _{SS} = 20 V, V _{GS} = 0 V	(Figure 1)	_	-	1	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$	(Figure 2)	_	-	±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} = 10 V, I _S = 1 mA	(Figure 3)	0.5	_	1.3	V
Forward Transconductance	9FS	V _{SS} = 10 V, I _S = 3 A	(Figure 4)	_	3.1	_	S
Static Source to Source On–State Resistance	R _{SS} (on)1	V _{GS} = 4.5 V, I _S = 3 A	(Figure 5)	24	39	45	mΩ
	R _{SS} (on)2	V _{GS} = 4.0 V, I _S = 3 A	(Figure 5)	25	41	48	mΩ
	R _{SS} (on)3	V _{GS} = 3.7 V, I _S = 3 A	(Figure 5)	27.5	43	50	mΩ
	R _{SS} (on)4	V _{GS} = 3.1 V, I _S = 3 A	(Figure 5)	31.5	48	57	mΩ
	R _{SS} (on)5	V _{GS} = 2.5 V, I _S = 3 A	(Figure 5)	33.5	58	72	mΩ
Turn-ON Delay Time	t _d (on)	V _{SS} = 10 V, V _{GS} = 4.5 V,	(Figure 6)	_	20	_	ns
Rise Time	t _r	I _S = 3 A		_	230	_	ns
Turn-OFF Delay Time	t _d (off)			_	130	_	ns
Fall Time	t _f	1		-	210	-	ns
Total Gate Charge	Qg	$V_{SS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{S} = 6 \text{ A}$	(Figure 7)	-	7	-	nC
Forward Source to Source Voltage	V _{F(S-S)}	I _S = 3 A, V _{GS} = 0 V	(Figure 8)	_	0.8	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

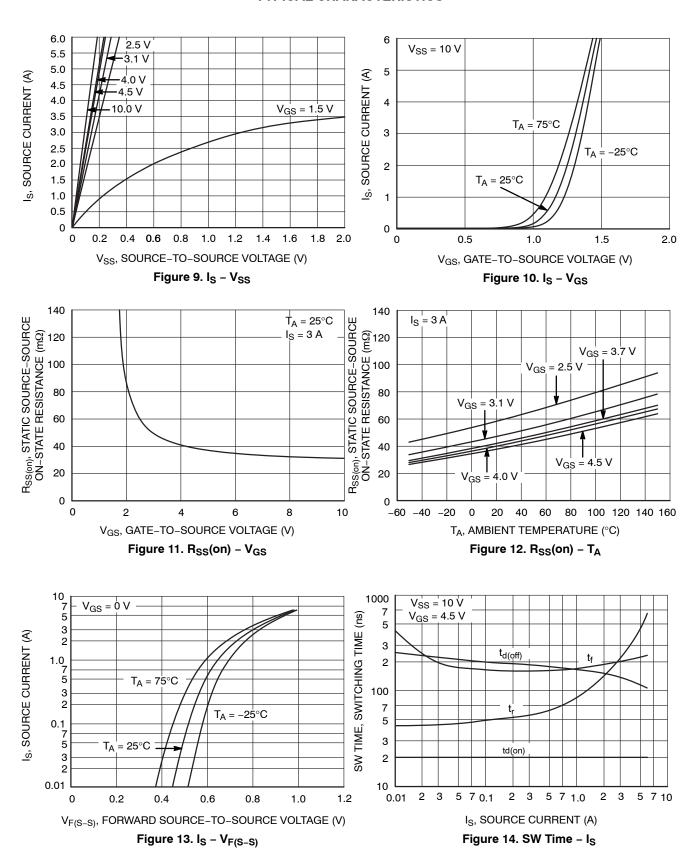
Test Circuit are Example of Measuring FET1 Side



NOTE: When FET2 is measured, the position of FET1 and FET2 is switched.

EFC4612R-S

TYPICAL CHARACTERISTICS



EFC4612R-S

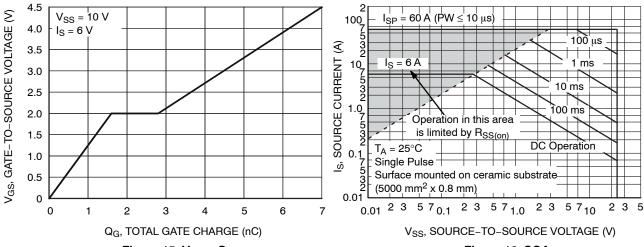


Figure 15. V_{GS} - Qg

Figure 16. SOA

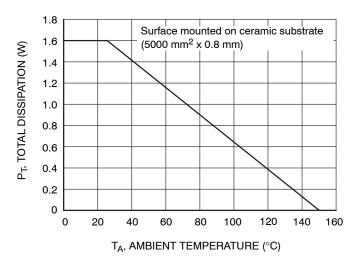


Figure 17. P_T - T_A

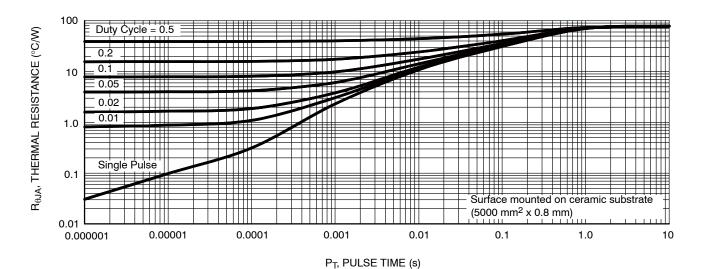


Figure 18. $R_{\theta JA}$ – Pulse Time

ORDERING INFORMATION

Device	Marking	Package	Shipping [†] (Qty / Packing)
EFC4612R-S-TR	FN	WLCSP4, 1.3 ×1.3 / EFCP1313-4CC-037 (Pb-Free and Halide Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSION

(Unit: mm)

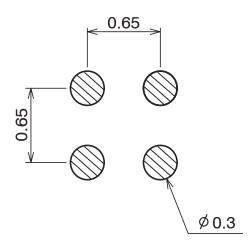
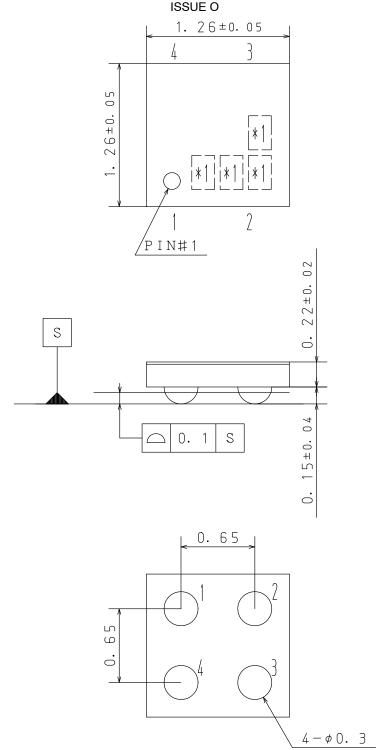


Figure 19. Recommended Soldering Footprint

WLCSP4, 1.3x1.3 / EFCP1313-4CC-037 CASE 567DP

DATE 29 FEB 2012



DOCUMENT NUMBER:	98AON67011E	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	WLCSP4 1.3X1.3 / EFCP1313-4CC-037		PAGE 1 OF 1	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warrantly, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales